

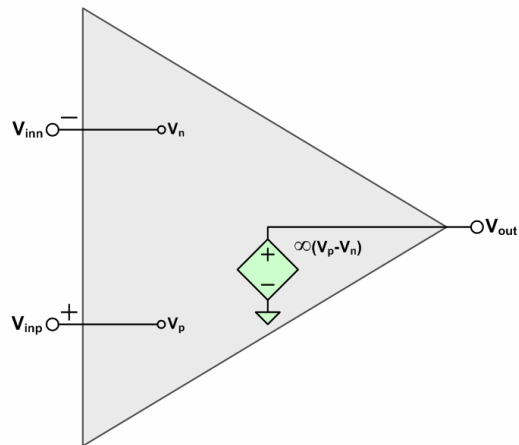
# Production Testing of Operational Amplifiers

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## Agenda

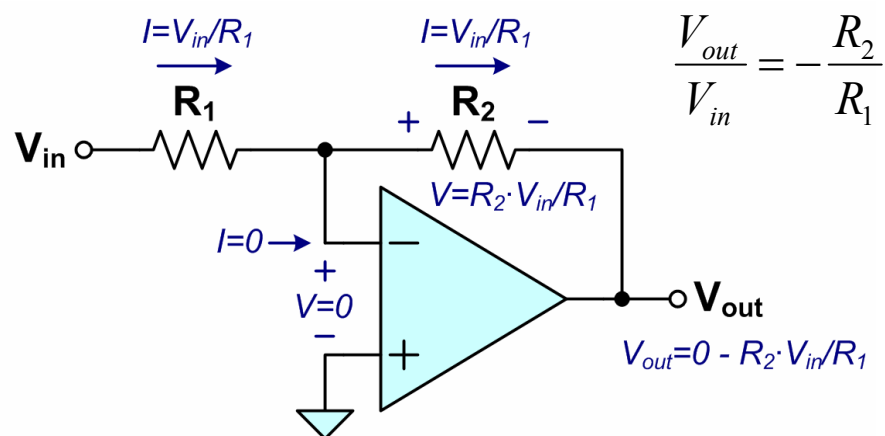
- Opamp Overview
- Production Test Strategy
- The Opamp Servo Loop
- DC Parameter Testing Methods
- Embedded Opamp Servo Loop
- Opamp Testing at TI

## Ideal OpAmp Model

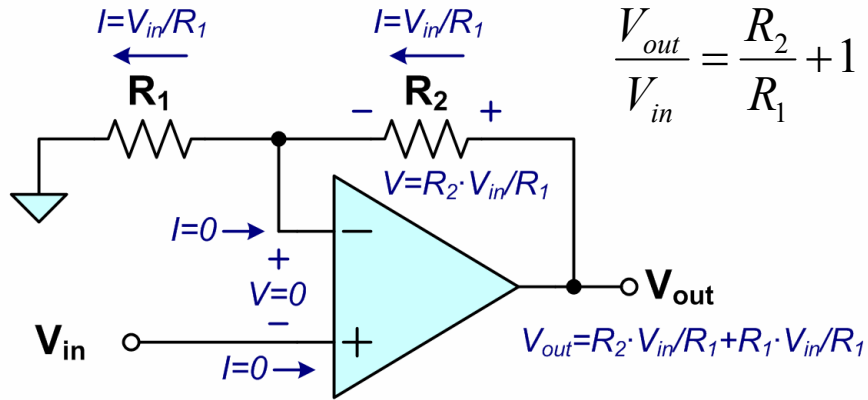


- No current flows into  $V_{inn}$  or  $V_{inp}$
- When operated in negative feedback,  $V_{inp} - V_{inn} = 0$

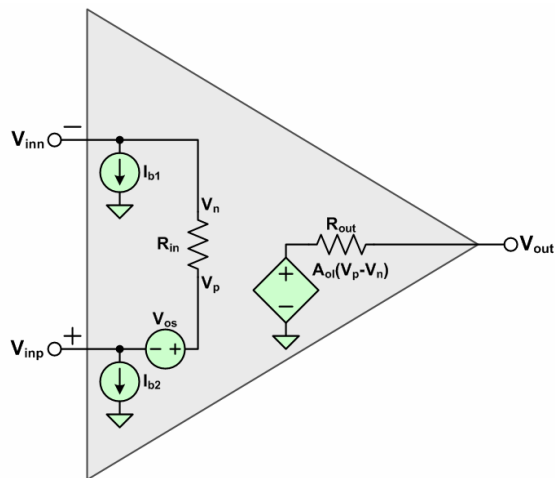
## Inverting Opamp Configuration



## Noninverting Opamp Configuration



## OpAmp DC Model with Imperfections



- $V_{inn}$  – Negative Input
- $V_{inp}$  – Positive Input
- $V_{out}$  – Output
- $I_{b1}, I_{b2}$  – Input Bias Current
- $R_{in}$  – Input Impedance
- $R_{out}$  – Output Impedance
- $V_{os}$  – Input Offset Voltage
- $A_{ol}$  – Open Loop Gain

## OpAmp - Typical Specs

OpAmp Characteristics	OPA277 <i>Low <math>V_{os}</math></i>	OPA129 <i>Low <math>I_B</math></i>	OPA627 <i><math>V_{os}/I_B/</math> <i>BW</i></i>	THS4031 <i>Hi BW</i>
Open Loop Gain ( $A_{ol}$ )	160db	120db	120db	98db
Input Offset Voltage ( $V_{os}$ )	5uV	0.5mV	40uV	0.5mV
Input Bias Current ( $I_B$ )	2.5nA	30fA	1pA	3uA
Input Offset Current ( $I_{os}$ )	2.5nA	30fA	0.5pA	30nA
Gain Bandwidth (BW)	8Mhz	1Mhz	16Mhz	100Mhz
Common Mode Rejection (CMRR)	138db	118db	116db	95db

- TI currently manufactures more than 1000 different opamp models!

## Production Testing Strategy

### Characterization vs. High Volume Production

- It is not cost effective to extensively test all parameters in production
- Generally a shorter test list is sufficient to guarantee performance
- Key data sheet and predictive parametric items should be selected

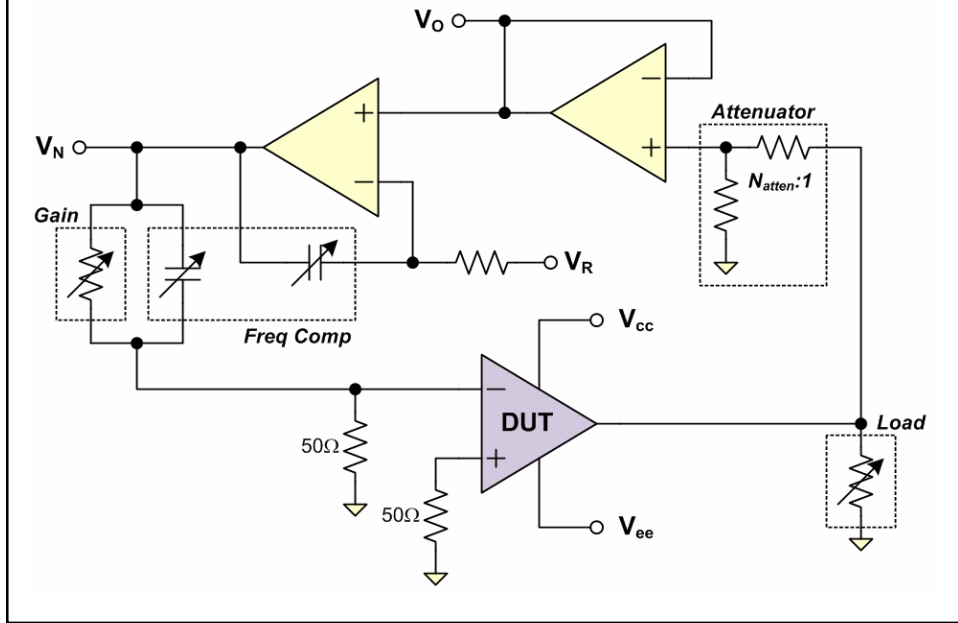
### AC vs. DC Testing

- Precision Opamps have a test list dominated by DC parameters
- High speed Opamps may have mostly AC parameters tested
- This presentation focuses on DC testing

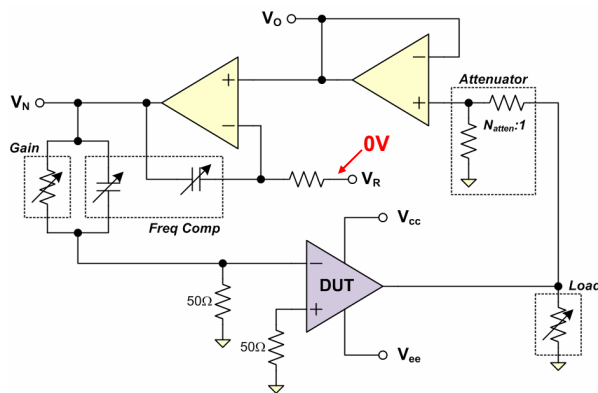
### Embedded vs. Standalone Opamps

- Embedded Opamps generally have a more limited test list and often operate with unipolar supplies
- This presentation focuses primarily on standalone Opamps

## OpAmp Servo Loop



## Input Offset Voltage ( $V_{os}$ )

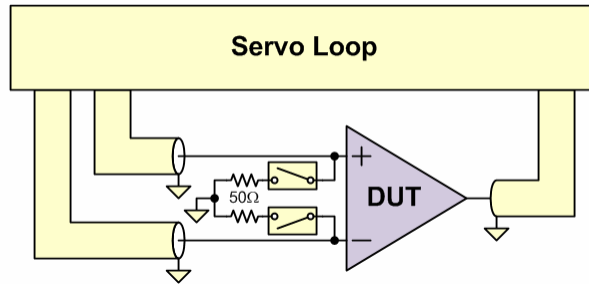


- Set  $V_{cc}$  and  $V_{ee}$  to desired voltages
- Connect desired Load
- Set Gain and Freq Comp
- Set  $V_R$  to 0V
- Measure  $V_N$

$$V_{OS} = \frac{V_N}{Gain}$$

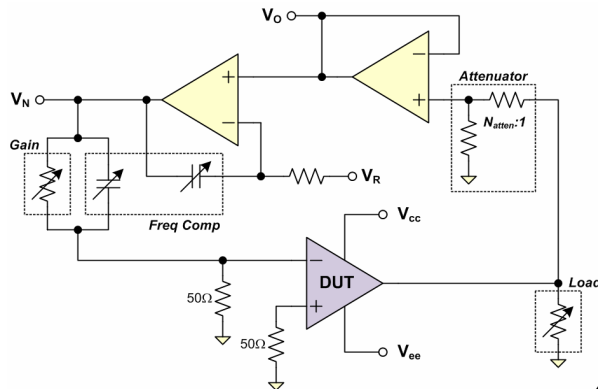
- The Gain should be chosen as large as possible such that worst case  $V_{os}$  will not saturate the servo amp (i.e.  $V_N$  will be saturated)
- Adjust Frequency Compensation to insure the loop does not oscillate

## Achieving Low $V_{os}$ Measurements



- The 50Ω terminations are generally part of the Servo Loop instrument
- Each point of interconnect between the Servo Loop and the DUT adds to the chance of thermal EMF voltage error (i.e. relays, connectors, etc)
- Thermal EMF occurs at dissimilar metal junctions with a thermal gradient
- Locating the termination near the DUT with Low EMF or Latching Relays greatly reduces the potential for  $V_{os}$  measurement error due to EMF

## Open Loop Gain ( $A_{ol}$ )

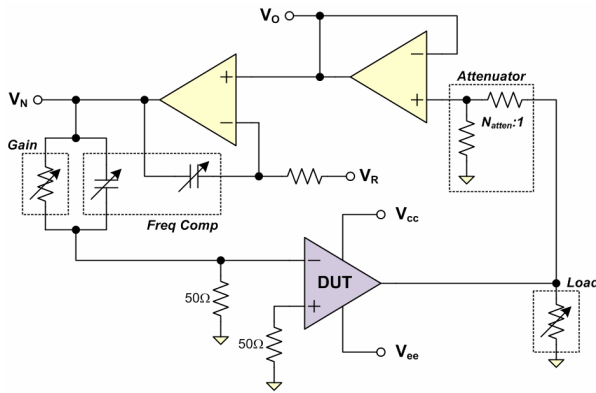


- Set  $V_{cc}$  and  $V_{ee}$  to desired voltage
- Connect desired Load
- Set Gain and Freq Comp
- Set  $V_R$  to  $V_{R1}$
- Measure  $V_{N1}$
- Set  $V_R$  to  $V_{R2}$
- Measure  $V_{N2}$

$$A_{ol} = \left| \frac{V_{R2} - V_{R1}}{V_{N2} - V_{N1}} \right| \cdot \frac{Gain}{N_{atten}}$$

- As in the  $V_{os}$  setup, it is critical to choose Gain and  $V_R$  levels such that  $V_N$  does not become saturated
- $A_{ol}$  is often reported in  $\mu V/V$  or dB units

## Common Mode Rejection Ratio (CMRR)

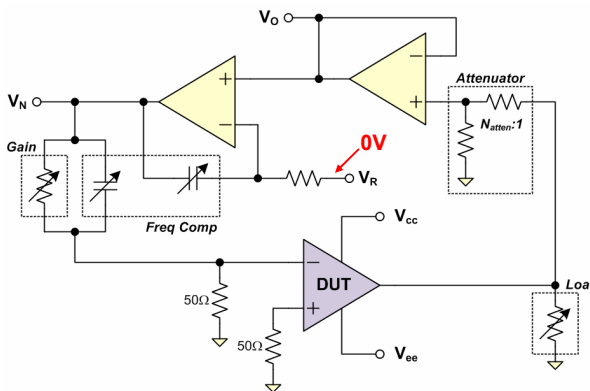


- Set  $V_{cc}$  and  $V_{ee}$  to desired voltage +  $V_{cmrpos}$
- Connect desired Load
- Set Gain and Freq Comp
- Set  $V_R$  to  $V_{cmrpos} / N_{atten}$
- Measure  $V_{N1}$
- Set  $V_{cc}$  and  $V_{ss}$  to desired voltage -  $V_{cmrneg}$
- Set  $V_R$  to  $V_{cmrneg} / N_{atten}$
- Measure  $V_{N2}$

$$CMRR = \left| \frac{V_{cmrpos} - V_{cmrneg}}{V_{N2} - V_{N1}} \right| \cdot Gain$$

- This method actually moves the power supplies and output and leaves the common mode at 0V. The net effect is the same, however.
- CMRR is often reported in uV/V or dB units

## Power Supply Rejection Ratio (PSRR)

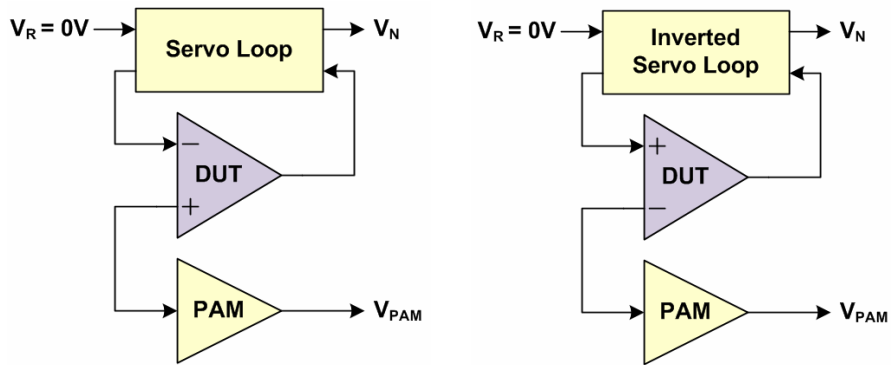


- Set  $V_{cc}$  and  $V_{ee}$  to minimum voltages
- Connect desired Load
- Set Gain and Freq Comp
- Set  $V_R$  to 0V
- Measure  $V_{N1}$
- Set  $V_{cc}$  and  $V_{ee}$  to maximum voltages
- Measure  $V_{N2}$

$$PSRR = \left| \frac{|\Delta V_{cc}| + |\Delta V_{ee}|}{V_{N1} - V_{N2}} \right| \cdot Gain$$

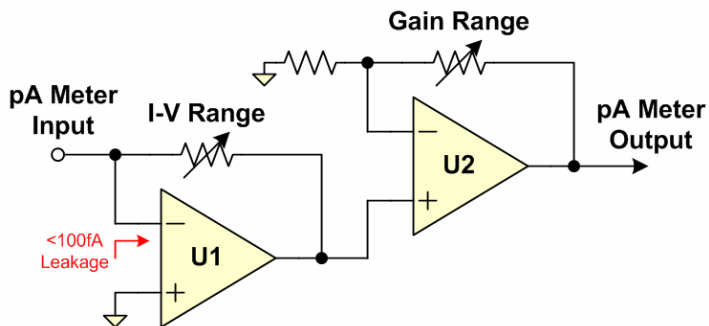
- This test can be combined with the  $V_{OS}$  test if the given supply values and load are acceptable
- PSRR is often reported in uV/V or dB units

## Input Bias Current ( $I_B$ ) – Picoamp Meter



- When  $I_B > \sim 250\text{pA}$ , the Picoamp Meter (PAM) is effective and efficient
- The Servo Loop must support Inverted operation to measure  $I_B$  on  $V_{INN}$
- The PAM is usually collocated with the Servo Loop

## Input Bias Current ( $I_B$ ) – Picoamp Meter...



- U1 forms an I-to-V converter and should be a low  $I_B$  opamp (OPA129)
- U2 forms a gain stage for ranging of the I-to-V output
- The  $V_{INP}$  terminal of U1 sets the Input Common Mode Voltage
- Open Socket Measurements should be made to negate stray leakage and the compounded offsets of U1 and U2



## Picoamp Meter Limitations

### Cleanliness

- Since the PAM is usually collocated with the Servo Loop, the path can be quite long. To keep stray leakage low, the entire path must be clean.
- Contamination can include: flux, finger oils, absorbed moisture, etc

### Dielectric Absorption

- Interconnect dielectrics suffer from “soakage” effects where charge becomes trapped and is slowly dissipated
- This can cause mysterious readings and excessive settling time

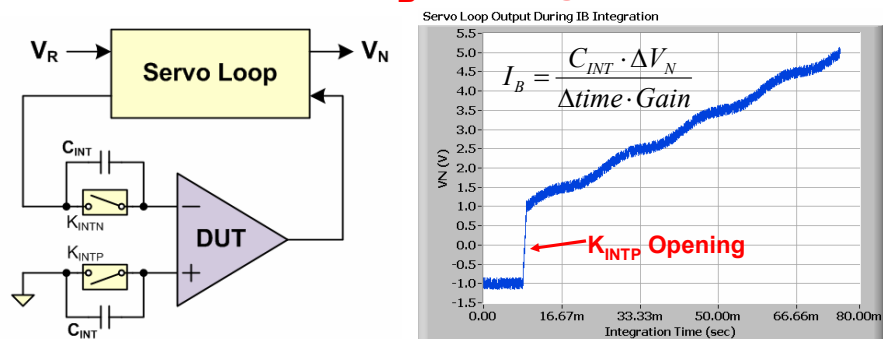
### Piezoelectric Charging

- Most coaxial cabling is susceptible to stray charging during flexure due to the piezoelectric effects of the braid rubbing against the dielectric

### I-to-V Input Leakage, Offset Stability, Etc...

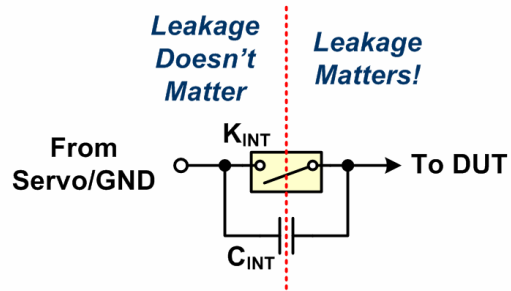
- U1 will ultimately limit the low end of measurement capability even in a perfect environment

## Input Bias Current ( $I_B$ ) – Integration Method



- $K_{INTP}$  and  $K_{INTN}$  are closed for normal operation (i.e.  $V_{OS}$ ,  $A_{OI}$ , etc)
- Opening one of the relays allows bias current to integrate into  $C_{INT}$
- Charge Injection during switching will cause a jump in  $V_N$  (coaxially shielded relays should be used to keep this manageable)
- Integration times set to a multiple of 16.6ms will reject 60Hz noise
- A typical choice for  $C_{INT}$  is a 1000pF WIMA Film

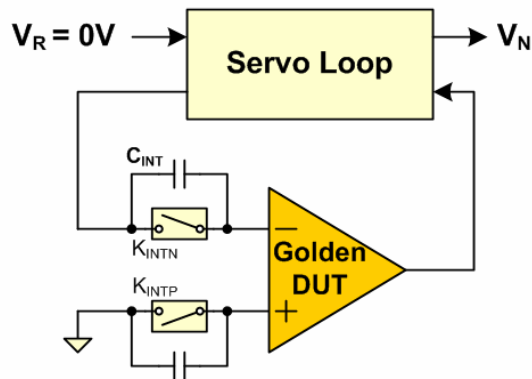
## Integration Method...



Leakage only matters on the DUT side of  $C_{INT}/K_{INT}$

- **Cleaning** – We must now only clean around the DUT
- **Dielectric Absorption** – Only PCB Dielectric around DUT +  $C_{INT}$
- **Piezoelectric Charging** – Effectively a non issue
- **Environmental Noise** – We can now easily integrate out 60Hz Noise
- **Opamp Limitations** – No Opamp needed, no issue

## Integration Method – Open Socket Cal...



Open Socket Calibration requires an Opamp to close the loop

- "Golden" data logged unit with known  $I_B$

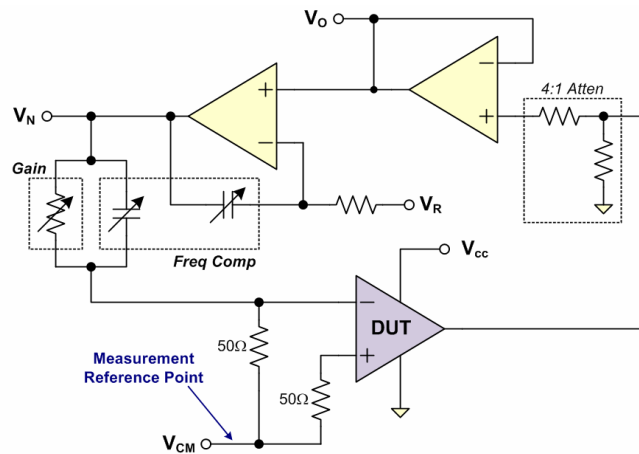
## Relating to Small Bias Currents...

- 1 Coulomb (C) of Charge =  $6.24 \times 10^{18}$  Electrons
- 1 Ampere (A) = 1 C/sec
- 1 femto Ampere (fA) =  $1 \times 10^{-15}$  A
- 1 fA =  $1 \times 10^{-15} \times 6.24 \times 10^{18} = 6240$  Electrons/sec
- 1 60Hz Line Cycle = 16.6 msec
- 1 fA over 1 Line Cycle =  $6240 \times 0.0166 = \sim 104$  Electrons
- **Small Bias Current measurement is about counting Electrons!**

## Tips for Measuring sub 10pA $I_B$

- DIB should be immaculate between  $C_{INT}/K_{INT}$  and Socket
- Baking the DIB can help drive out excess absorbed moisture
- Some types of sockets can have higher background leakage and dielectric absorption
- Some types of low  $I_B$  Opamps can trap charge in their input stages if not handled carefully resulting in erratic  $I_B$  measurements
- Use an ionizer
- Keep stray unionized air flow away
- Integrate over multiple line cycles
- Data logged "Golden" unit for offset cal

## Embedded Opamps



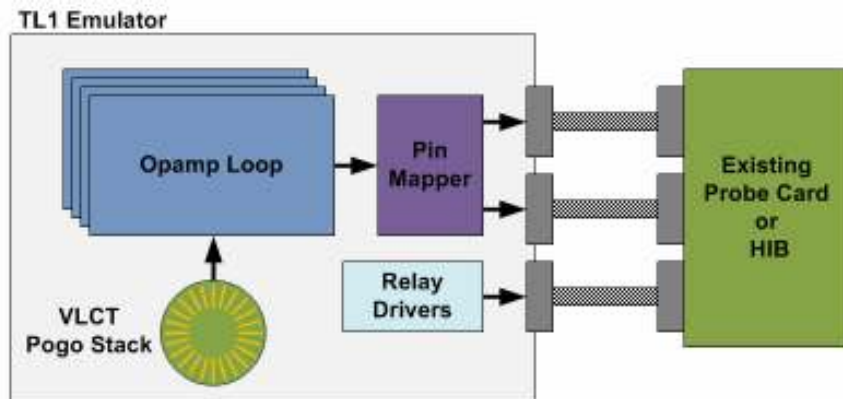
- Embedded Opamps generally do not have bipolar power supplies
- A  $V_{CM}$  is required to insure a legal common mode input voltage
- All measurements should be with respect to  $V_{CM}$

## TL1 – TI Legacy Opamp Tester



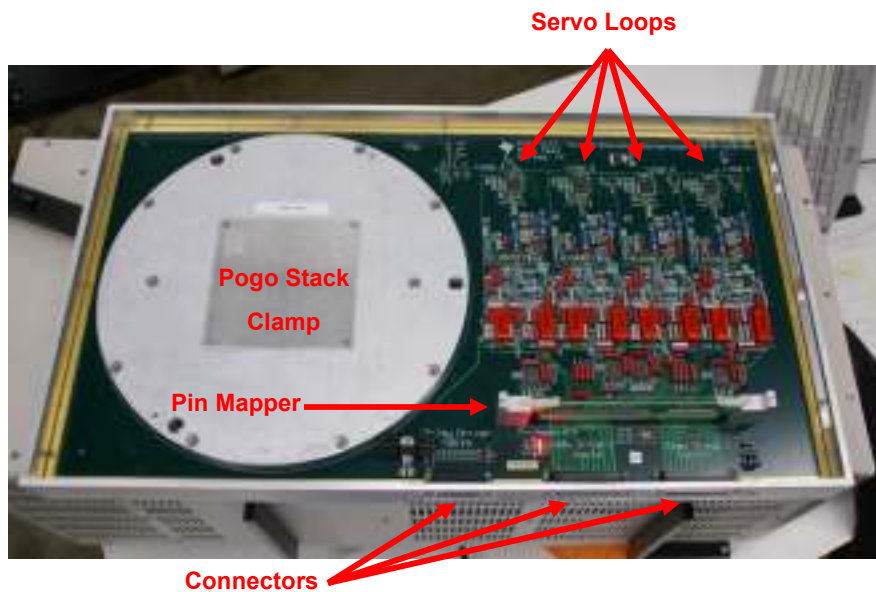
- Early 1980s era internally developed Opamp Tester

## Retiring the TL1 – Emulation

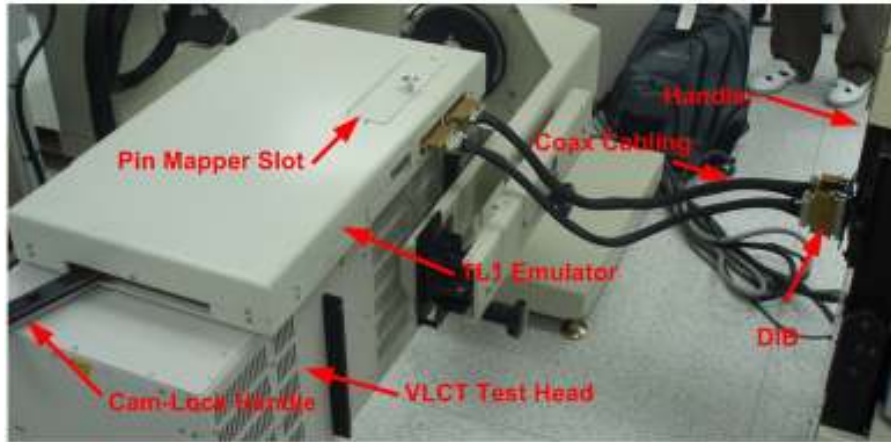


- “Add On” developed for our internal low cost tester to emulate the TL1
- Existing Probe Cards and HIBs were reused
- Rapid program migration tools were developed to speed conversions

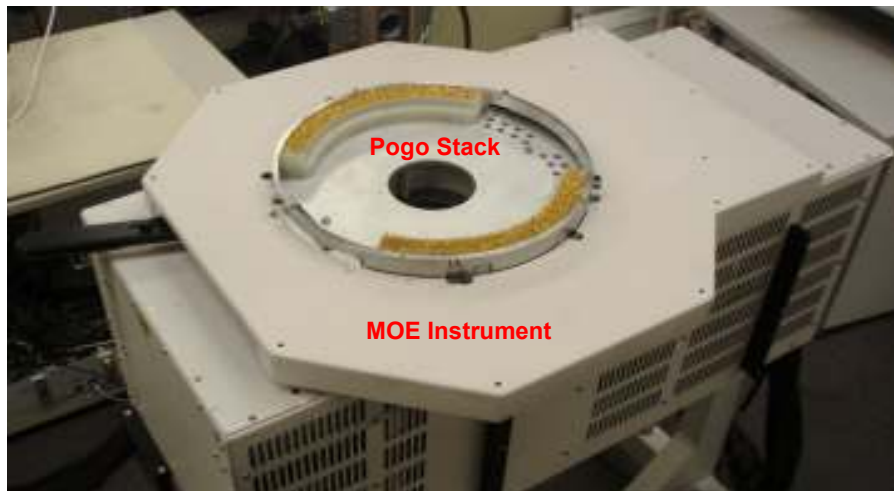
## TL1 Emulator - Insides



## TL1 Emulator – Connected to Handler



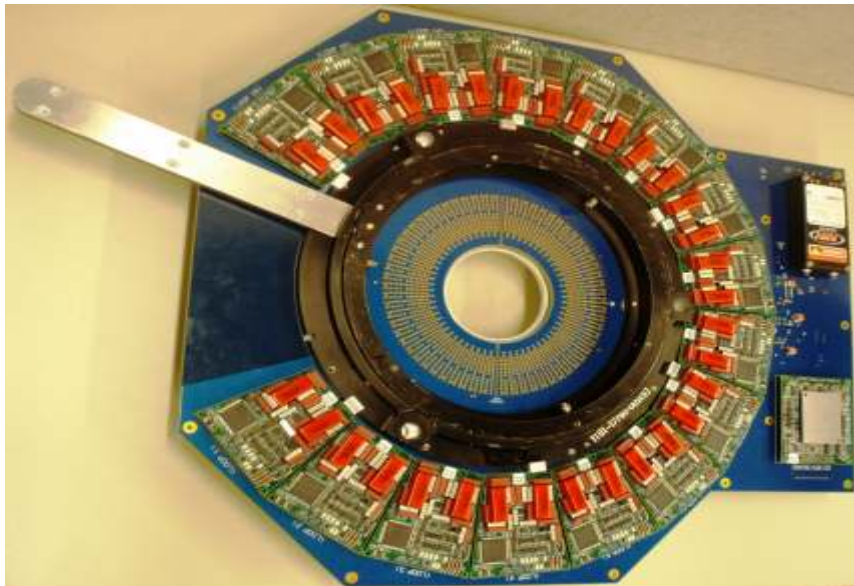
## Increasing Throughput – Multisite Opamp Emulator (MOE)



## MOE with Quad site SOIC DIB



## MOE – Loop Modules



**Contact Information...**

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